

LME49726 High Current, Low Distortion, Rail-to-Rail Output Audio Operational Amplifier

Check for Samples: LME49726

FEATURES

- Rail-to-Rail Output
- Easily Drives 2kΩ Loads to within 4mV of Each Power Supply Voltage Rail
- Optimized for Superior Audio Signal Fidelity
- Output Short Circuit Protection
- High Output Drive (>300mA)
- Available in VSSOP Exposed-DAP Package

KEY SPECIFICATIONS

- Power Supply Voltage Range: 2.5 to 5.5 V
- Quiescent Current per Amplifier at 5V: 0.7 mA (Typ)
- THD+N, $A_V = 1$, $f_{IN} = 1$ kHz, $R_L = 10$ k Ω :
 - $(V_{OUT} = 3.5V_{P-P}, V_{DD} = 5.0V)$: 0.00008 % (Typ)
 - $(V_{OUT} = 1.5V_{P-P}, V_{DD} = 2.5V)$: 0.00002 % (Typ)
- Equivalent Input Noise (f = 10k): 8.3 nV/√Hz (Typ)
- Slew Rate: ±3.7 V/µs (Typ)
- Gain Bandwidth Product: 6.25 MHz (Typ)
- Open Loop Gain (R_L = 10kΩ): 120 dB (Typ)
- Input Bias Current: 0.2 pA (Typ)
- Input Offset Voltage: 0.5 mV (Typ)
- PSRR (DC): 104 dB (Typ)

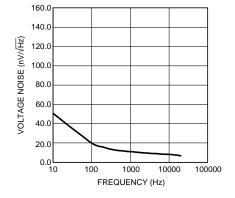


Figure 1. Input Voltage Noise vs Frequency $V_{DD} = 3V$

APPLICATIONS

- Portable Audio Amplification
- Preamplifiers and Multimedia
- Equalization and Crossover Networks
- Line Drivers and Receivers
- Active Filters
- DAC I-V Converter Gain Stage
- ADC Front-End Signal Conditioning

DESCRIPTION

The LME49726 is a low distortion, low noise rail-torail output audio operational amplifier optimized and fully specified for high performance, high fidelity applications. The LME49726 delivers superior audio amplification for outstanding signal audio performance. The LME49726 has a very low THD+N to easily satisfy demanding audio applications. To ensure that the most challenging loads are driven without compromise, the LME49726 provides output current greater than 300mA at 5V. Further, dynamic range is maximized by an output that drives 2kΩ loads to within 4mV of either power supply voltage.

The LME49726 has a supply range of 2.5V to 5.5V. Over this supply range the LME49726's input circuitry maintains excellent common-mode and power supply rejection, as well as maintaining its low input bias current. The LME49726 is unity gain stable.

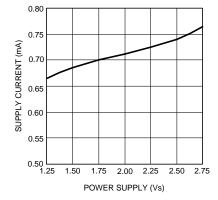


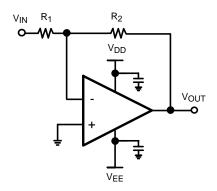
Figure 2. Supply Current vs Supply Voltage per Amplifier, $R_L = No Load$, $A_V = -1$

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Typical Connections



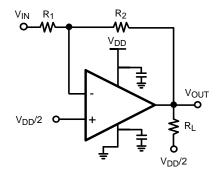


Figure 3. Inverting Configuration Split Supplies

Figure 4. Inverting Configuration Single Supplies

Connection Diagram

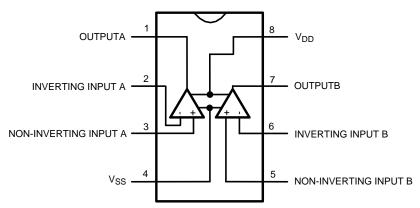


Figure 5. See Package Number DGN0008A





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS(1)(2)(3)

Input Voltage Output Short Circuit ⁽⁴⁾ Power Dissipation ESD Rating ⁽⁵⁾ ESD Rating ⁽⁶⁾ Junction Temperature (V _{SS}) – 0.7V to (V _{DD}) + Continuation (V _{SS}) – 0.7V to (V _{SS}) + Continuation (V _{SS}) – 0.7V to (V _{SS}) + Continuation (V _{SS}) – 0.7V to (V _{SS}) + Continuation (V _{SS}) – 0.7V to (V _{SS}) + Continuation (V _{SS}) – 0.7V to (V _{SS}) + Continuation (V _{SS}) – 0.7V to (V _{SS}) + Continuation (V _{SS}) – 0.7V to (V _{SS}) + Continuation (V _{SS}) – 0.7V to (V _{SS}) + Continuation (V _{SS}) – 0.7V to (V _{SS}) + Continuation (V _{SS}) – 0.7V to (V _{SS}) + Continuati			
	Power Supply Voltage	$V_S = V_{SS} - V_{DD}$	6V
Output Short Circuit ⁽⁴⁾ Power Dissipation ESD Rating ⁽⁵⁾ ESD Rating ⁽⁶⁾ Junction Temperature	Storage Temperature		−65°C to 150°C
Power Dissipation ESD Rating ⁽⁵⁾ ESD Rating ⁽⁶⁾ Junction Temperature	Input Voltage		$(V_{SS}) - 0.7V$ to $(V_{DD}) + 0.7V$
ESD Rating ⁽⁵⁾ ESD Rating ⁽⁶⁾ Junction Temperature	Output Short Circuit (4)		Continuous
ESD Rating ⁽⁶⁾ Junction Temperature	Power Dissipation		Internally Limited
Junction Temperature	ESD Rating ⁽⁵⁾		2000V
	ESD Rating ⁽⁶⁾		200V
Thermal Resistance 9 (DGN0008A) 72	Junction Temperature		150°C
UA (/	Thermal Resistance	θ _{JA} (DGN0008A)	72°C/W

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions. All voltages are measured with respect to the ground pin, unless otherwise specified.
- (2) The Electrical Characteristics tables list specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not ensured.
- (3) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (4) The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{JMAX}, θ_{JA}, and the ambient temperature, T_A. The maximum allowable power dissipation is P_{DMAX} = (T_{JMAX} T_A) / θ_{JA} or the number given in Absolute Maximum Ratings, whichever is lower.
- (5) Human body model, applicable std. JESD22-A114C.
- (6) Machine model, applicable std. JESD22-A115-A.

OPERATING RATINGS(1)

Temperature Range	$T_{MIN} \le T_A \le T_{MAX}$	-40°C ≤ T _A ≤ 125°C
Supply Voltage Range		2.5V ≤ V _S ≤ 5.5V

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions. All voltages are measured with respect to the ground pin, unless otherwise specified.

Product Folder Links: LME49726



ELECTRICAL CHARACTERISTICS ($V_{DD} = 5.0V$ and $V_{DD} = 2.5V$)

The following specifications apply for the circuit shown in Figure 1. V_{DD} = 5.0V and V_{DD} = 2.5V, V_{SS} = 0.0V, V_{CM} = $V_{DD/2}$, R_L = 10k Ω , C_{LOAD} = 20pF, f_{IN} = 1kHz, BW = 20–20kHz, and T_A = 25°C, unless otherwise specified.

Symbol	Borometer	Conditions	LME4	19726	Units
Symbol	Parameter	Conditions	Typical ⁽¹⁾	Limit ⁽²⁾	(Limits)
TUDAN	Tarable and State of National Nation	$\begin{aligned} A_V &= -1,\ V_{OUT} = 3.5 V_{p-p},\ V_{DD} = 5 V \\ R_L &= 600 \Omega \\ R_L &= 2 k \Omega \\ R_L &= 10 k \Omega \end{aligned}$	0.0008 0.0002 0.0008		% % %
THD+N	Settling time Settling time Equivalent Input Noise Voltage Equivalent Input Noise Density Current Noise Density Input Offset Voltage Vos/ΔTemp Average Input Offset Voltage Drift vs Temperature SRR Power Supply Rejection Ratio Channel-to-Channel Isolation Input Bias Current Input Bias Current Input Bias Current Input Bias Current Drift vs Temperature Input Offset Current Common-Mode Input Voltage Range MRR Common Mode Rejection Ratio If Corner Frequency	$\begin{array}{l} A_V = -1, \ V_{OUT} = 1.5 V_{p-p}, \ V_{DD} = 2.5 V \\ R_L = 600 \Omega \\ R_L = 2 k \Omega \\ R_L = 10 k \Omega \end{array}$	0.001 0.0008 0.0002		% % %
GBWP	Gain Bandwidth Product		6.25	5.0	MHz (min)
SR	Slew Rate	$A_V = +1, R_L = 10k\Omega$	3.7	2.5	V/µs (min)
t _s	Settling time	A _V = 1V step 0.1% error range 0.001% error range	800 1.2		ns µs
e _N	Equivalent Input Noise Voltage	f _{BW} = 20Hz to 20kHz (A-weighted)	0.7	1.25	μV _{RMS} (max)
		f = 10kHz	8.3		nV / √Hz
e _N	Equivalent Input Noise Density	f = 1kHz	10		nV / √Hz
		f = 100Hz	24		nV / √Hz
I _N	Current Noise Density	f = 1kHz	0.75		pA / √Hz
Vos	Input Offset Voltage	$V_{IN} = V_{DD/2}, V_O = V_{DD/2}, A_V = 1$	0.5	2.25	mV (max)
ΔV _{OS} /ΔTemp		40°C ≤ T _A ≤ 85°C	1.2		μV/°C
PSRR	Power Supply Rejection Ratio	2.5 to 5.5V, V _{CM} = 0, V _{DD} /2	104	85	dB (min)
ISO _{CH-CH}	Channel-to-Channel Isolation	f _{IN} = 1kHz	94		dB
I _B	Input Bias Current	$V_{CM} = V_{DD}/2$	±0.2		pA
ΔI _{OS} /ΔTemp	•	-40°C ≤ T _A ≤ 85°C	35		nA/°C
Ios	Input Offset Current	$V_{CM} = V_{DD}/2$	±0.2		pA
V _{IN-CM}	Common-Mode Input Voltage Range			V _{DD} -1.6 V _{SS} +0.1	V (min)
CMRR	Common Mode Rejection Ratio	0.1V < V _{DD} - 1.6V	95	80	dB (min)
1/f	1/f Corner Frequency		2		kHz
A _{VOL}	Open-Loop Voltage Gain	$V_{OUT} = V_{DD}/2$	120	100	dB (min)
		$R_L = 2k\Omega$ to $V_{DD}/2$	V _{DD} -0.004 V _{SS} +0.004		V (min) V (max)
VOUTSWING	Maximum Output Voltage Swing	$R_L = 16\Omega$ to $V_{DD}/2$	V _{DD} -0.33 V _{SS} +0.33		V (min) V (max)
1	Output Current	$V_{OUT} = 5V$, $V_{DD} = 5V$	350		mA
lout	Output Ourient	$V_{OUT} = 2.5V, V_{DD} = 2.5V$	160		mA
la	Quiescent Current per Amplifier	$I_{OUT} = 0mA, V_{DD} = 5V$	0.7	1.1	mA (max)
I _S	Quioscont Gunent per Ampinier	$I_{OUT} = 0$ mA, $V_{DD} = 2.5$ V	0.64	1.0	mA (max)

⁽¹⁾ Typical values represent most likely parametric norms at $T_A = +25$ °C, and at the Recommended Operation Conditions at the time of product characterization and are not ensured.

Datasheet min/max specification limits are specified by test or statistical analysis.

Product Folder Links: LME49726

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TYPICAL PERFORMANCE CHARACTERISTICS

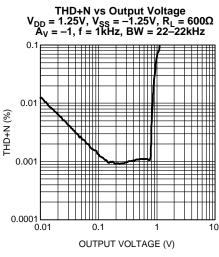


Figure 6.

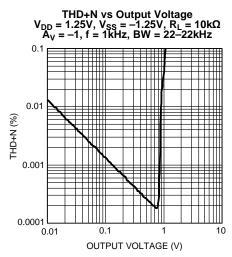


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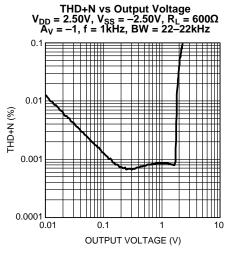


Figure 10.

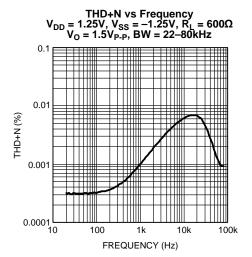


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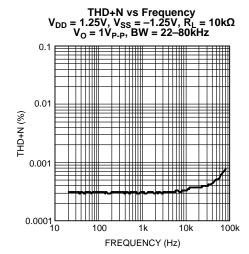


Figure 9.

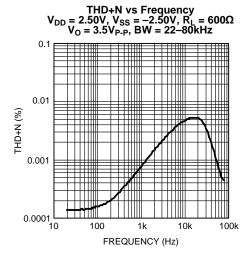


Figure 11.



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

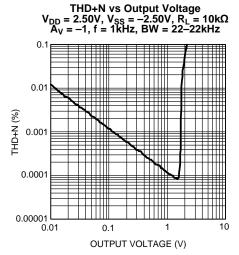


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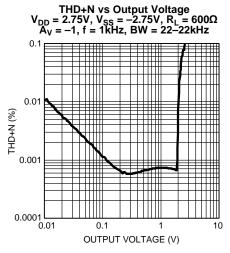


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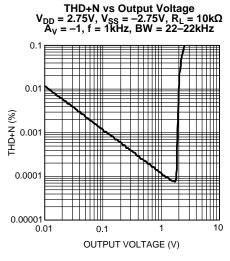


Figure 16.

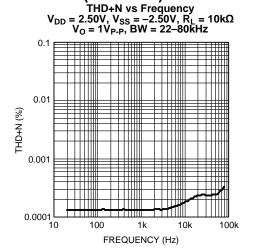


Figure 13.

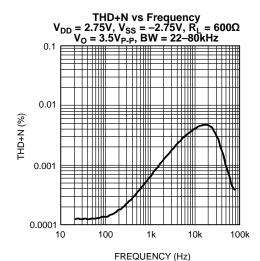


Figure 15.

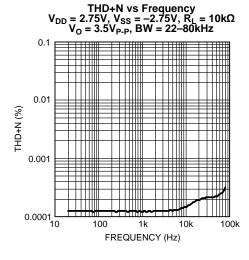


Figure 17.



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

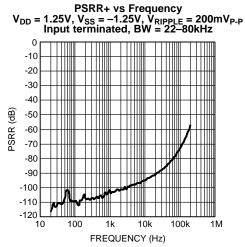


Figure 18.

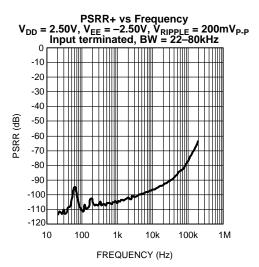


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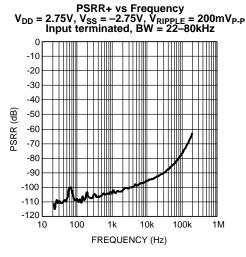


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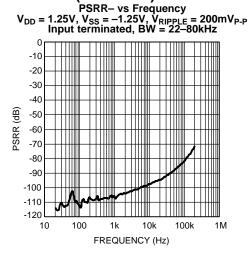


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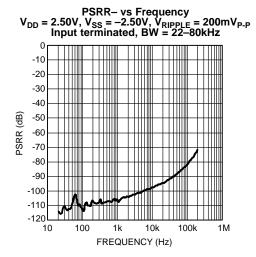


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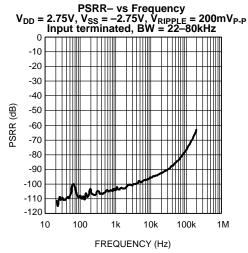


Figure 23.

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

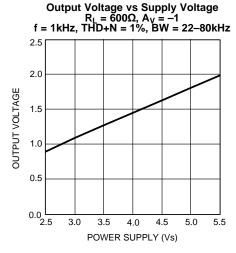


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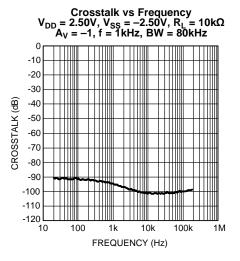


Figure 26.

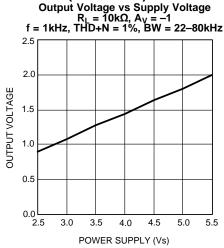


Figure 25.

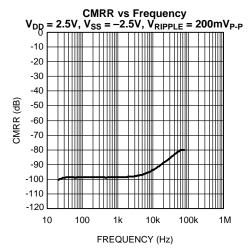
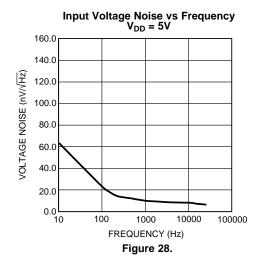


Figure 27.





APPLICATION INFORMATION

DISTORTION MEASUREMENTS

The vanishingly low residual distortion produced by LME49726 is below the capabilities of all commercially available equipment. This makes distortion measurements just slightly more difficult than simply connecting a distortion meter to the amplifier's inputs and outputs. The solution, however, is quite simple: an additional resistor. Adding this resistor extends the resolution of the distortion measurement equipment.

The LME49726's low residual is an input referred internal error. As shown in Figure 29, adding the 10Ω resistor connected between athe amplifier's inverting and non-inverting inputs changes the amplifier's noise gain. The result is that the error signal (distortion) is amplified by a factor of 101. Although the amplifier's closed-loop gain is unaltered, the feedback available to correct distortion errors is reduced by 101. To ensure minimum effects on distortion measurements, keep the value of R1 low as shown in Figure 29.

This technique is verified by duplicating the measurements with high closed loop gain and/or making the measurements at high frequencies. Doing so, produces distortion components that are within measurement equipment capabilities. This datasheet's THD+N and IMD values were generated using the above described circuit connected to an Audio Precision System Two Cascade.

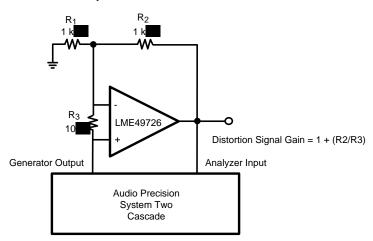


Figure 29. THD+N and IMD Distortion Test Circuit

OPERATING RATINGS AND BASIC DESIGN GUIDELINES

The LME49726 has a supply voltage range from +2.5V to +5.5V single supply or ±1.25 to ±2.75V dual supply.

Bypassed capacitors for the supplies should be placed as close to the amplifier as possible. This will help minimize any inductance between the power supply and the supply pins. In addition to a $10\mu F$ capacitor, a $0.1\mu F$ capacitor is also recommended in CMOS amplifiers.

The amplifier's inputs lead lengths should also be as short as possible. If the op amp does not have a bypass capacitor, it may oscillate.

BASIC AMPLIFIER CONFIGURATIONS

The LME49726 may be operated with either a single supply or dual supplies. Figure 2 shows the typical connection for a single supply inverting amplifier. The output voltage for a single supply amplifier will be centered around the common-mode voltage, V_{CM} . Note, the voltage applied to the V_{CM} insures the output stays above ground. Typically, the V_{CM} should be equal to $V_{DD}/2$. This is done by putting a resistor divider circuit at this node, see Figure 30.

Product Folder Links: LME49726



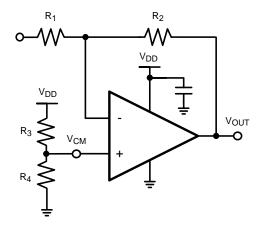


Figure 30. Single Supply Inverting Op Amp

Figure 31 shows the typical connection for a dual supply inverting amplifier. The output voltage is centered on zero.

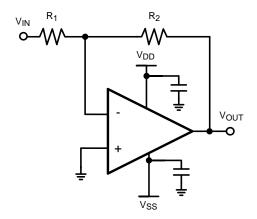


Figure 31. Dual Supply Inverting Configuration

Figure 32 shows the typical connection for the Buffer Amplifier or also called a Voltage Follower. The Buffer is a unity gain stable amplifier.

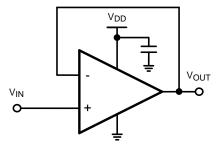
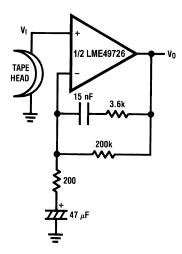


Figure 32. Unity-Gain Buffer Configuration

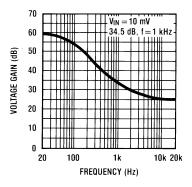


Typical Applications



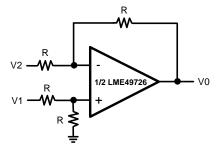
 $A_V = 34.5$ F = 1 kHz $E_n = 0.38 \text{ }\mu\text{V}$ A Weighted

Figure 33. NAB Preamp



 $A_V = 34.5$ F = 1 kHz $E_n = 0.38 \text{ }\mu\text{V}$ A Weighted

Figure 34. NAB Preamp Voltage Gain vs Frequency

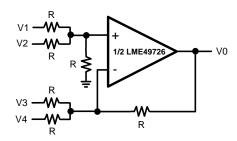


 $V_O = V1-V2$

Figure 35. Balanced to Single Ended Converter

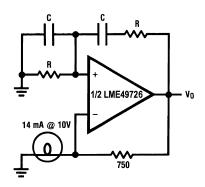
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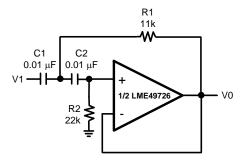
$$V_0 = V1 + V2 - V3 - V4$$

Figure 36. Adder/Subtracter



$$f_0 = \frac{1}{2\pi RC}$$

Figure 37. Sine Wave Oscillator



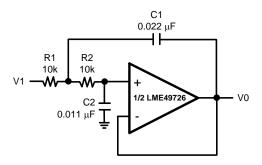
if C1 = C2 = C $R1 = \frac{\sqrt{2}}{2\omega_0C}$ $R2 = 2 \bullet R1$ Illustration is $f_0 = 1 \text{ kHz}$

Figure 38. Second Order High Pass Filter (Butterworth)

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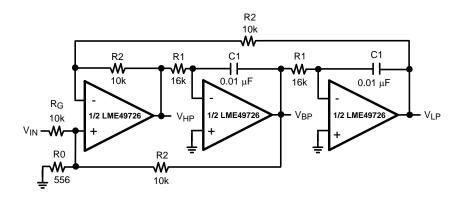


$$C1 = \frac{\sqrt{2}}{\omega_0 F}$$

$$C2 = \frac{C1}{2}$$

Illustration is $f_0 = 1 \text{ kHz}$

Figure 39. Second Order Low Pass Filter (Butterworth)



$$f_0 = \frac{1}{2\pi C 1R1}, Q = \frac{1}{2} \left(1 + \frac{R2}{R0} + \frac{R2}{RG} \right), A_{BP} = QA_{LP} = QA_{LH} = \frac{R2}{RG}$$

Illustration is $f_0 = 1 \text{ kHz}$, Q = 10, $A_{BP} = 1$

Figure 40. State Variable Filter

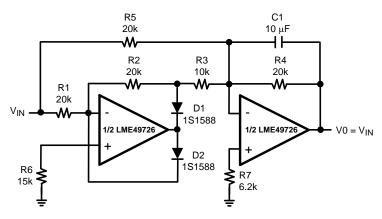


Figure 41. AC/DC Converter

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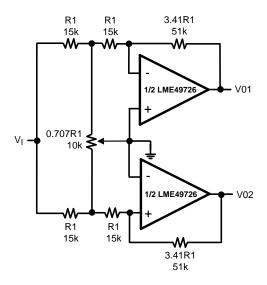


Figure 42. 2 Channel Panning Circuit (Pan Pot)

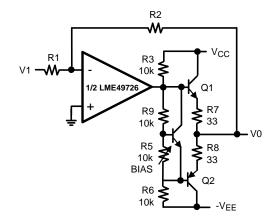
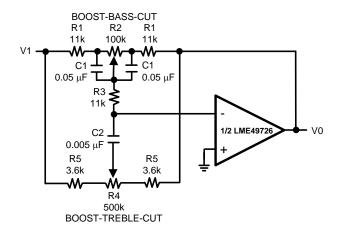


Figure 43. Line Driver





$$\begin{split} f_L &= \frac{1}{2\pi R2C1}, f_{LB} = \frac{1}{2\pi R1C1} \\ f_H &= \frac{1}{2\pi R5C2}, f_{HB} = \frac{1}{2\pi (R1 + R5 + 2R3)C2} \\ Illustration is: \\ f_L &= 32 \ Hz, f_{LB} = 320 \ Hz \\ f_H &= 11 \ kHz, f_{HB} = 1.1 \ kHz \end{split}$$

Figure 44. Tone Control

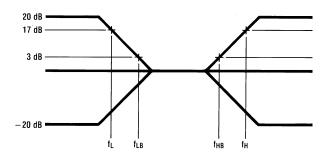
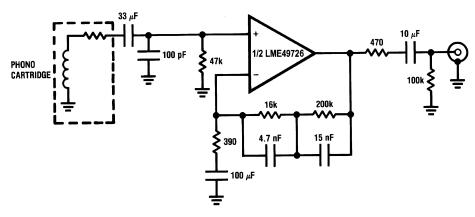


Figure 45.

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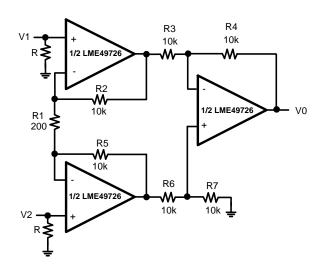
Product Folder Links: *LME49726*





 $\begin{array}{l} A_v = 35 \text{ dB} \\ E_n = 0.33 \text{ } \mu\text{V} \\ \text{S/N} = 90 \text{ dB} \\ \text{f} = 1 \text{ kHz} \\ \text{A Weighted}, \text{ V}_{\text{IN}} = 10 \text{ mV} \\ \text{@f} = 1 \text{ kHz} \end{array}$

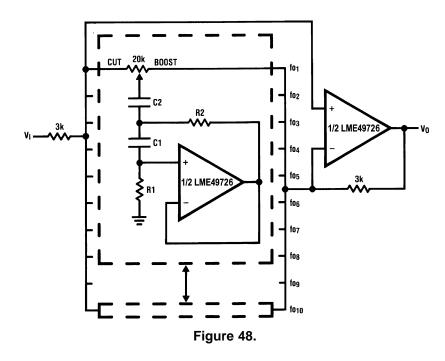
Figure 46.



If R2 = R5, R3 = R6, R4 = R7 $V0 = \left(1 + \frac{2R2}{R1}\right) \frac{R4}{R3} (V2 - V1)$ Illustration is: V0 = 101 (V2 - V1)

Figure 47. Balanced Input Mic Amp





fo (Hz)	C ₁	C ₂	R ₁	R ₂
32	0.12µF	4.7µF	75kΩ	500Ω
64	0.056µF	3.3µF	68kΩ	510Ω
125	0.033µF	1.5µF	62kΩ	510Ω
250	0.015μF	0.82µF	68kΩ	470Ω
500	8200pF	0.39µF	62kΩ	470Ω
1k	3900pF	0.22µF	68kΩ	470Ω
2k	2000pF	0.1µF	68kΩ	470Ω
4k	1100pF	0.056µF	62kΩ	470Ω
8k	510pF	0.022µF	68kΩ	510Ω
16k	330pF	0.012µF	51kΩ	510Ω
At volume of change = ±12	dB Q = 1.			

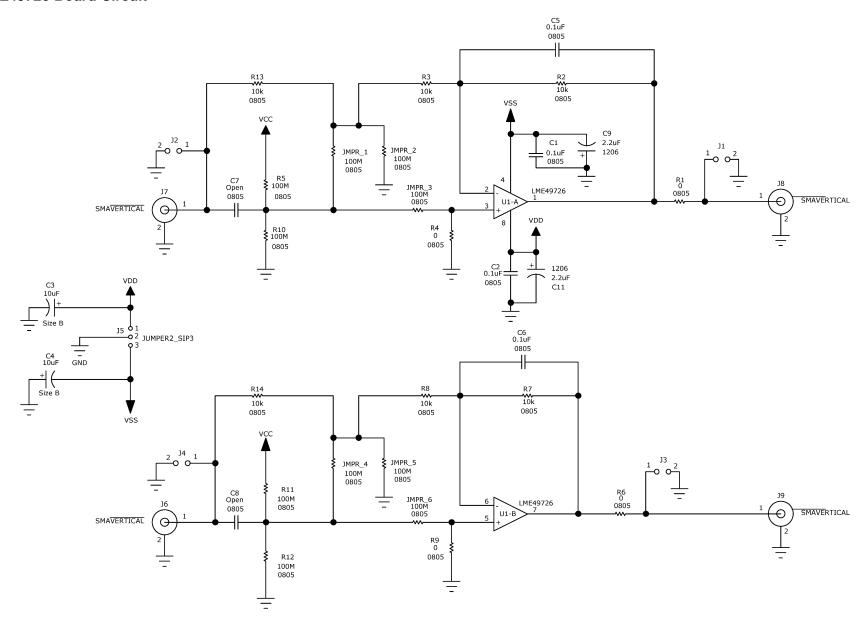
LME49726 Bill of Materials

Description	Designator	Designator Part Number		Quantity/Brd	
Ceramic Capacitor 0.1uF, 10%, 50V 0805 SMD	C1, C2, C5–C8	08055C104KAT2A	AVX	2	
Tantalum Capacitor 2.2uF,10%, 20V, A-size	C9, C11	T491A225K020AT	K020AT Kemet		
Tantalum Capacitor 10uF,10%, 20V, B-size	C3, C4	T491B106K020AT Kemet		2	
Resistor 0Ω, 1/8W 1% 0805 SMD	R1, R4, R6, R9, R13, R14	CRCW08050000Z0EA	Vishay	6	
Header, 2-Pin	JP1, JP2, JP3, JP4	HDR1X2	Header 2	4	
Header, 3-Pin	JP5	HDR1X3	Header 3	1	
Resistor 10kΩ, 1/8W 1% 0805 SMD	R2, R3, R7, R8	CRCW080510K0FKEA	Vishay	4	
Dual Rail-to-Rail Op Amp	U1	LME49726	Texas Instruments	1	
Resistor 100meg/open 1/8W 0805 SMD	R5, R10, R11, R12	OPEN N/A	N/A	0	

Product Folder Links: LME49726



LME49726 Board Circuit





LME49726 Demo Board Views

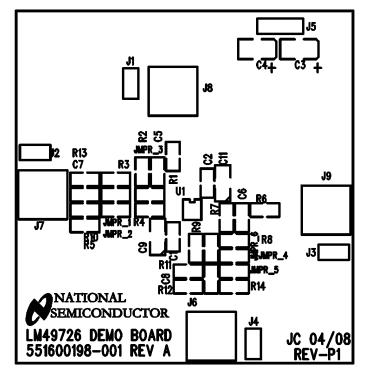


Figure 49. Top Silkscreen

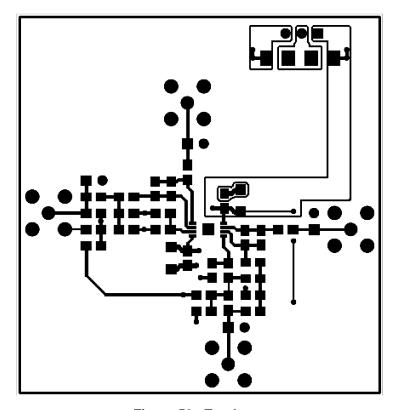


Figure 50. Top Layer



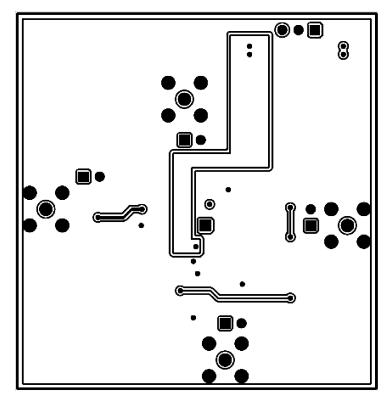


Figure 51. Bottom Layer



REVISION HISTORY

Rev	Date	Description
1.0	11/05/08	Initial release.
1.01	05/25/10	Increased Operating Temperature Range.
1.02	07/14/11	Added curves 30038602 and 03 and input text edits.
1.03	07/19/11	Re-released the D/S to the WEB after adding curves 30038602 and 03.
С	04/04/13	Changed layout of National Data Sheet to TI format.

Product Folder Links: LME49726

www.ti.com 11-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
LME49726MY/NOPB	Active	Production	HVSSOP (DGN) 8	1000 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	ZA3
LME49726MY/NOPB.A	Active	Production	HVSSOP (DGN) 8	1000 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	ZA3
LME49726MYX/NOPB	Active	Production	HVSSOP (DGN) 8	3500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	ZA3
LME49726MYX/NOPB.A	Active	Production	HVSSOP (DGN) 8	3500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	ZA3

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

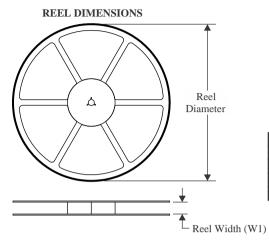
⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

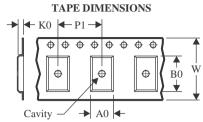
⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE MATERIALS INFORMATION

www.ti.com 1-Aug-2025

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LME49726MY/NOPB	HVSSOP	DGN	8	1000	177.8	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LME49726MYX/NOPB	HVSSOP	DGN	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

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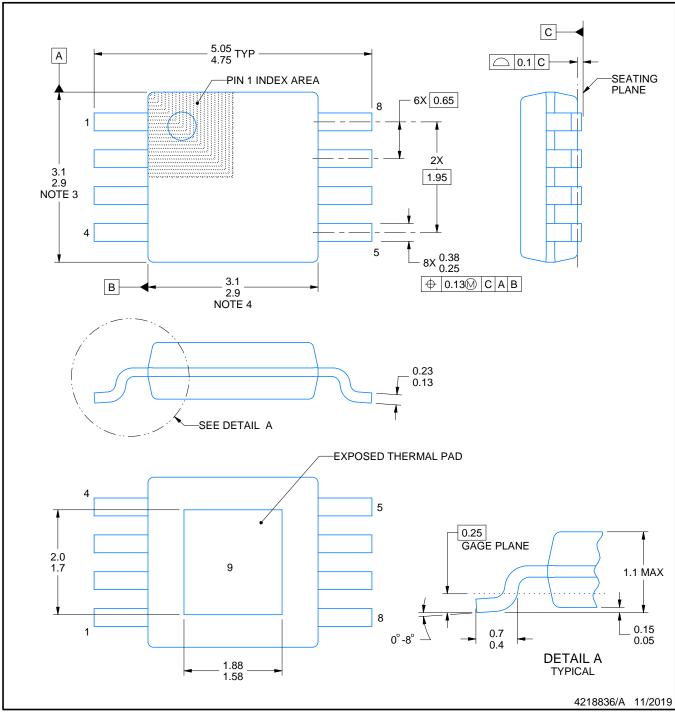


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LME49726MY/NOPB	HVSSOP	DGN	8	1000	208.0	191.0	35.0
LME49726MYX/NOPB	HVSSOP	DGN	8	3500	367.0	367.0	35.0

$\textbf{PowerPAD}^{^{\text{\tiny{TM}}}}\,\textbf{VSSOP - 1.1 mm max height}$

SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

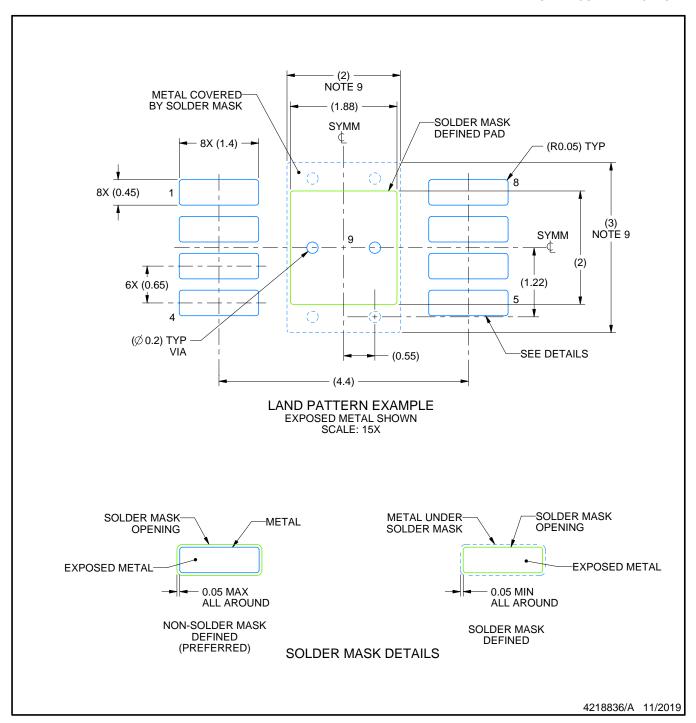
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



SMALL OUTLINE PACKAGE

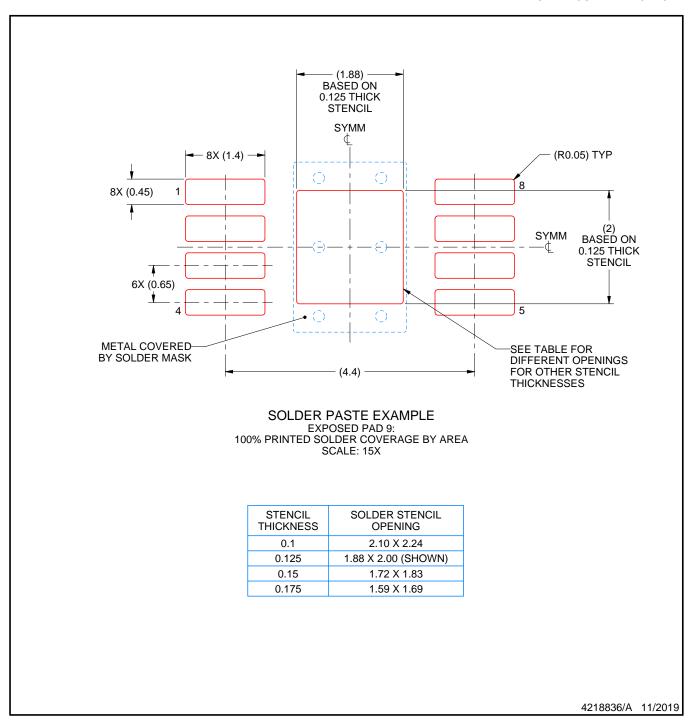


NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 11. Board assembly site may have different recommendations for stencil design.



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